

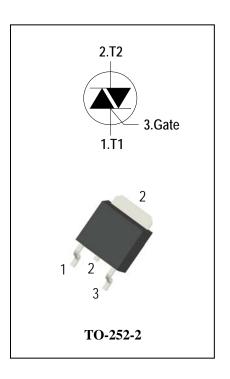
3 Quadrants High temperature Triacs

General Description

High current density due to mesa technology , guaranteed maximum junction temperature 150° C. The ADS6CH triac series is suitable for general purpose AC switching. They can beused as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers. The heatsink can be reduced,compared to traditional triacs, according to the high performance at given junction temperatures.

Features

- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current (IT(RMS)= 6A)
- ◆ High Commutation dv/dt
- ◆ High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant



Absolute Maximum Ratings

Symbol	Items	Conditions		Ratings	Unit
V_{DRM}	Denetitive Deals Off Chate Valtage	T: - 25°C	ADS6CH60E	600	V
V_{RRM}	Repetitive Peak Off-State Voltage	Tj = 25°C	ADS6CH80E	800	V
$I_{T(RMS)}$	R.M.S On-State Current	T _C = 110 °C		6	Α
I _{TSM}	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		60/63	Α
l ² t	I ² t for fusing	tp=10ms		20	A ² s
-11/-14	Critical rate of rise of on-state F = 120 Hz Tj = 150°C			50	A/µs
dI/dt	current	I _G = 2 x I _{GT} , tr ≤ 100 ns			
I_{GM}	Peak Gate Current	tp = 20 μs Tj = 150°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=150°C)			1	W
P_GM	Peak Gate Power Dissipation(tp=20us,Tj=150°C)			5	W
Tj	Operating Junction Temperature			- 40 ~ 150	°C
T _{STG}	Storage Temperature			- 40 ~ 150	°C

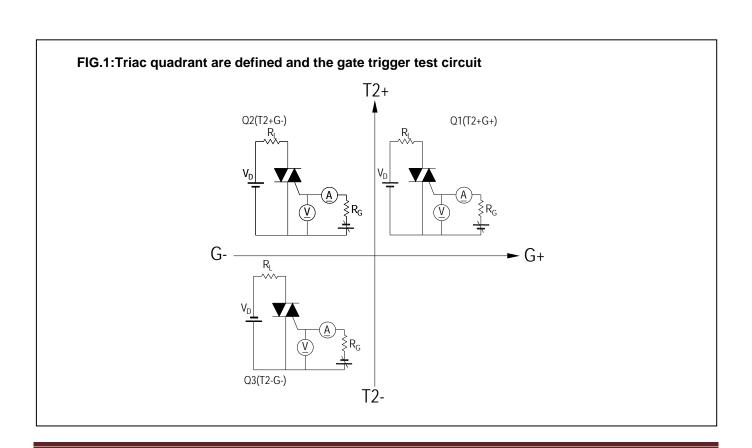






Electrical Characteristics(Tj = 25°C unless otherwise specified)

Symbol	Items		Conditions		ADS6CH60		80E	Unit
-					S	Blank	В	
I _{DRM}	Peak Forward Reverse Blocking		$V_{DRM} = V_{RRM}$, $Tj = 25$ °C	May	5		uA	
I _{RRM}	Current		$V_{DRM} = V_{RRM}$, $Tj = 150$ °C	Max.	2.7		mA	
V_{TM}	Peak On-S	tate Voltage	I_{TM} = 8.5A, t_p = 380 μ s	Max.	1.5		V	
V_{GD}	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 150^{\circ}\text{C}$	Min.	0.2		V	
V_{GT}	Q1-Q2-Q3	Gate Trigger Voltage	V 40V D 200	Max.	1.5		V	
I _{GT}	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$, $R_L = 33\Omega$	Max.	10	35	50	mA
I _H	Q1-Q2-Q3	Holding Current	I _T = 0.1A	Max.	20	45	60	mA
	Q1-Q3	Lotobing Current	1 - 121	Max.	20	50	70	mA
IL	Q2	Latching Current	I _G = 1.2 I _{GT}		35	70	100	
dV/dt	Critical Rate of Rise of Off-State Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 150°C	Min.	200	1000	1500	V/µs
(dV/dt)c	Critical Rate of Change of Commutating Voltage		V_D =400V Tj = 150°C (dl/dt)c=-2.6A/ms	Min.	1	15	20	V/µs
R _{th(j-c)}	Junction to case (AC)			Max.	2.5			°C/W
R _{th(j-a})	Junction to ambient(Copper surface under tab:S=0.5cm ²)			Max.	70			°C/W



ADV

FIG.2: Maximum on-state power dissipation

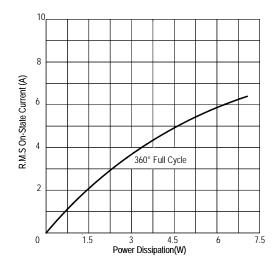


FIG.4: Maximum transient thermal impedance

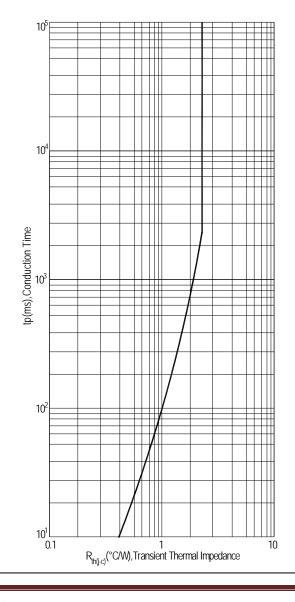


FIG.3: Typical RMS on-state current VS Allowable case Temperature

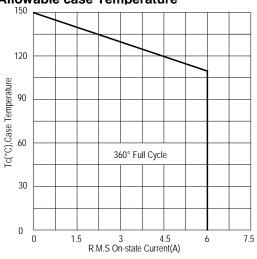


FIG.5: Rated surge on-state current (Non-Repetitive)

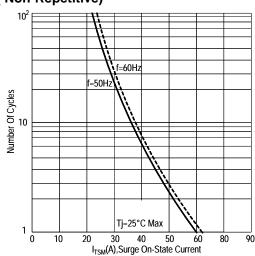
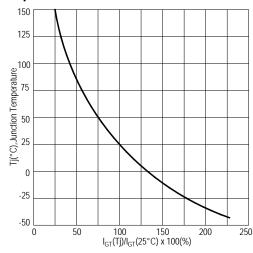


FIG.6: Gate trigger current VS Junction temperature





ADS6CH60E/80E

FIG.7:Holding current and Latching current VS Junction temperature

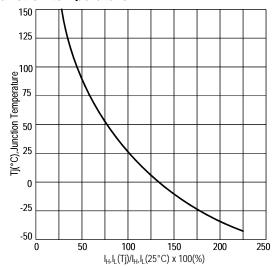
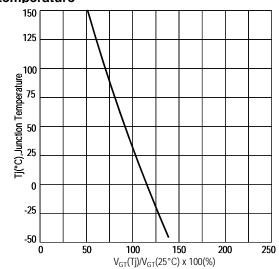
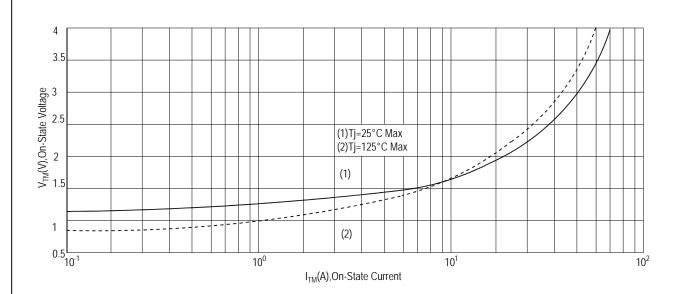


FIG.9: On-state characteristics(Max)

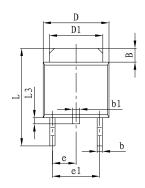
FIG.8: Gate trigger voltage VS Junction temperature

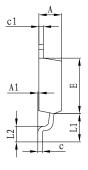


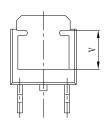




PACKAGE MECHANICAL DATA TO-252-2 Package Dimension







Cumb	Dimer	nsions	Dimensions		
Symb	In Millimeters		In Inches		
ol	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
В	1.350	1.650	0.053	0.065	
b	0.500	0.700	0.020	0.028	
b1	0.700	0.900	0.028	0.035	
С	0.450	0.620	0.017	0.024	
c1	0.450	0.620	0.017	0.024	
D	6.350	6.650	0.250	0.262	
D1	5.100	5.400	0.200	0.213	
E	5.900	6.200	0.232	0.244	
е	2.300	TYP.	0.091 TYP.		
e1	4.500	4.700	0.177	0.185	
L	9.500	10.60	0.374	0.396	
L1	2.550	2.900	0.100	0.114	
L2	1.400	1.780	0.055	0.070	
L3	0.600	0.900	0.024	4 0.035	
V	4.100 REF.		0.161 REF.		

Making Diagram



ADV:Logo ADS6CH60EB:Part number X:Internal control code H:Halogen Free AD S 6 C H 60 E

ADVANCED

Internal control code

Current: 6-6A

Quadrant: C=3Q

High temperature: H=150°C

S(B)
Sensitivity and type:
S=10mA
Blank=35mA
B=50mA
Package explain:E=TO-252-2
Voltage:60=600V 80=800V

Ordering information

Part number	Package	Marking	Packing	Quantity	
ADS6CH60E#	TO-252-2	ADS6CH60E#	Tube	80pcs	
ADS0CH00E#			Embossed tape	2500pcs	
ADS6CH80E#	TO-252-2	ADS6CH80E#	Tube	80pcs	
ADS0CH00E#			Embossed tape	2500pcs	
Note:# = Gate Trigger Current Sensitivity and type					



ADS6CH60E/80E

Notice

- 1. All information included in this document such as product data, diagrams, charts, programs, algorithms, and application circuit examples, is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any ADV products listed in this document, please confirm the latest product information with a ADV sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by ADV such as that disclosed through our website. (http://www.advsemi.com)
- 2. ADV has used reasonable care in compiling the information included in this document, but ADV assumes no liability whatsoever for any damages incurred as a result of errors or omissions in the information included in this document.
- 3. You should use the products described herein within the range specified by ADV, especially with respective the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. ADV shall have no liability for malfunctions or damages arising out of the use of ADV products beyond such specified ranges.
- 4. When using or otherwise relying on the information in this document, you should evaluate the information in light of the total system before deciding about the applicability of such information to the intended application. ADV makes no representations, warranties or guaranties regarding the suitability of its products for any particular application and specifically disclaims any liability arising out of the application and use of the information in this document or ADV products.
- 5. Although ADV endeavors to improve the quality and reliability of its products, IC products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Please be sure to implement safety measures to guard against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a ADV product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other applicable measures. Among others, since the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by vou.
- 6. This document is provided for reference purposes only so that ADV customers may select the appropriate ADV products for their use. ADV neither makes warranties or representations with respect to the accuracy or completeness of the information contained in this document nor grants any license to any intellectual property rights or any other rights of ADV or any third party with respect to the information in this document.
- 7. ADV shall have no liability for damages or infringement of any intellectual property or other rights arising out of the use of any information in this document, including, but not limited to, product data, diagrams, charts, programs, algorithms, and application circuit examples.
- 8. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written approval from ADV.

6 / 6 www.advsemi.com Feb,2013 -Rev.3.02